## NSN 5961-00-421-0832

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View Online at https://aerobasegroup.com/nsn/5961-00-421-0832 **Inclosure Material:** Metal **Overall Length:** 0.350 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Npn **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 1.8 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 10.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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